

General Description

The LTA2904H is a dual-channel industry-standard operational amplifier with supply voltage up to +40 V. The LTA2904H offers outstanding dc precision and ac performance, including low offset (± 0.8 mV typically), low offset drift (± 7 $\mu\text{V}/^\circ\text{C}$ typically), 1.1 MHz bandwidth, and 40 nV/ $\sqrt{\text{Hz}}$ input voltage noise density at 1 kHz. Unique features such as differential input-voltage range to the negative supply rail, high output current (± 30 mA), high capacitive load drive of up to 0.1 nF, and high slew rate (0.5 V/ μs) make the LTA2904H a high-performance operational amplifiers for high-voltage industrial applications.

The robust design of the LTA2904H provides ease-of-use to the circuit designer: integrated RF/EMI rejection filter and high electro-static discharge (ESD) protection (2000V for HBM). The LTA2904H is optimized for operation at voltages from +4.5 V (± 2.25 V) to +40 V (± 20 V) over the extended temperature range of -40 $^\circ\text{C}$ to $+125$ $^\circ\text{C}$.

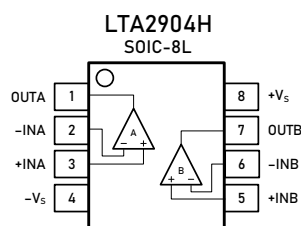
Features and Benefits

- Wide Supply: ± 2.25 V to ± 20 V, 4.5 V to 40 V
- Low Offset Voltage: ± 0.8 mV Typically
- Low Offset Voltage Drift: ± 7 $\mu\text{V}/^\circ\text{C}$
- High Common-Mode Rejection: 80 dB
- Gain Bandwidth: 1.1 MHz
- Slew Rate: 0.5 V/ μs
- Low Noise: 40 nV/ $\sqrt{\text{Hz}}$ at 1 kHz
- Low Quiescent Current: 300 μA per amplifier
- Low Bias Current: ± 10 nA

Applications

- Merchant network and server power supply units
- Power Delivery: UPS, Server, and Merchant Network Power
- Programmable Logic Controllers
- Multi-function printers
- Power supplies and mobile chargers
- Motor control: AC induction, brushed DC, Brushless DC, high-voltage, low-voltage, permanent magnet, and stepper motor
- Desktop PC and motherboard
- Indoor and outdoor air conditioners
- Washers, dryers, and refrigerators
- AC inverters, string inverters, central inverters, an voltage frequency drives
- Electronic point-of-sale systems

Pin Configuration (Top View)



Pin Description

Symbol	Description
-IN	Inverting input of the amplifier. The voltage range is from V_{S-} to $V_{S+} - 2\text{ V}$.
+IN	Non-inverting input of the amplifier. This pin has the same voltage range as -IN.
+ V_S	Positive power supply. The voltage is from 4.5 V to 40 V. Split supplies are possible as long as the voltage between V_{S+} and V_{S-} is from 4.5 V to 40 V.
- V_S	Negative power supply. It is normally tied to ground. It can also be tied to a voltage other than ground as long as the voltage between V_{S+} and V_{S-} is from 4.5 V to 40 V.
OUT	Amplifier output.
NC	No connection

Ordering Information ⁽¹⁾

Type Number	Package Name	Package Quantity	Eco Class ⁽²⁾	Marking Code ⁽³⁾
LTA2904HXS8/R8	SOIC-8L	Tape and Reel, 4 000	Green (RoHS & no Sb/Br)	HV2904

- (1) Please contact to your Linearin representative for the latest availability information and product content details.
- (2) Eco Class - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & Halogen Free).
- (3) There may be multiple device markings, a varied marking character of "x" , or additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

Limiting Value - In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Absolute Maximum Rating
Supply Voltage, V_{S+} to V_{S-}	60 V
Signal Input Terminals: Voltage, Current	$-V_S - 0.3\text{ V}$ to $+V_S + 0.3\text{ V}$, $\pm 10\text{ mA}$
Output Short-Circuit	Continuous
Storage Temperature Range, T_{stg}	-65 to $+150\text{ }^\circ\text{C}$
Junction Temperature, T_j	$150\text{ }^\circ\text{C}$
Lead Temperature Range (Soldering 10 sec)	$260\text{ }^\circ\text{C}$

ESD Rating

Parameter	Item	Value	Unit
Electrostatic Discharge Voltage	Human body model (HBM), per MIL-STD-883J / Method 3015.9 ⁽¹⁾	2 000	V
	Charged device model (CDM), per ESDA/JEDEC JS-002-2014 ⁽²⁾	1 500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible if necessary precautions are taken.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible if necessary precautions are taken.

Electrical Characteristics

$V_S = 4.5 \text{ V to } 40 \text{ V}$, $T_A = +25 \text{ }^\circ\text{C}$, $V_{CM} = V_{OUT} = V_S/2$, and $R_L = 10 \text{ k}\Omega$ connected to $V_S/2$, unless otherwise noted. Boldface limits apply over the specified temperature range, $T_A = -40 \text{ }^\circ\text{C to } +125 \text{ }^\circ\text{C}$.

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
OFFSET VOLTAGE						
Input offset voltage	V_{OS}			± 0.8	± 3	mV
Offset voltage drift	$V_{OS \text{ TC}}$	$T_A = -40 \text{ to } +125 \text{ }^\circ\text{C}$		± 7		$\mu\text{V}/^\circ\text{C}$
Power supply rejection ratio	PSRR	$V_S = 4.5 \text{ to } 40 \text{ V}$, $V_{CM} = 0.1 \text{ V}$		5		$\mu\text{V}/\text{V}$
		$T_A = -40 \text{ to } +125 \text{ }^\circ\text{C}$		10		
INPUT BIAS CURRENT						
Input bias current	I_B			10		nA
		$T_A = -40 \text{ to } +85 \text{ }^\circ\text{C}$		90		
		$T_A = -40 \text{ to } +125 \text{ }^\circ\text{C}$		250		
Input offset current	I_{OS}			5		nA
NOISE						
Input voltage noise	V_n	$f = 0.1 \text{ to } 10 \text{ Hz}$		5		μV_{P-P}
Input voltage noise density	e_n	$f = 1 \text{ kHz}$		40		$\text{nV}/\sqrt{\text{Hz}}$
Input current noise density	I_n	$f = 1 \text{ kHz}$		5		$\text{fA}/\sqrt{\text{Hz}}$
INPUT VOLTAGE						
Common-mode voltage range	V_{CM}		$-V_S$		$+V_S - 2$	V
Common-mode rejection ratio	CMRR	$V_{CM} = 0.1 \text{ to } 38 \text{ V}$, $T_A = -40 \text{ to } +125 \text{ }^\circ\text{C}$		80		dB
INPUT IMPEDANCE						
Input capacitance	C_{IN}	Differential		2		pF
		Common mode		3.5		
OPEN-LOOP GAIN						
Open-loop voltage gain	A_{VOL}	$V_S = 40 \text{ V}$, $V_O = 0.1 \text{ to } 39.9 \text{ V}$		126		dB
		$T_A = -40 \text{ to } +125 \text{ }^\circ\text{C}$		118		
		$V_S = 5 \text{ V}$, $V_O = 0.1 \text{ to } 4.9 \text{ V}$		116		
		$T_A = -40 \text{ to } +125 \text{ }^\circ\text{C}$		108		
FREQUENCY RESPONSE						
Gain bandwidth product	GBW			1.1		MHz
Slew rate	SR	$V_S = 40 \text{ V}$, $G = +1$, 10 V step		0.5		$\text{V}/\mu\text{s}$
Total harmonic distortion + noise	THD+N	$G = +1$, $f = 1 \text{ kHz}$, $V_O = 3 V_{RMS}$		0.001		%
Settling time	t_S	To 0.1%, $V_S = 40 \text{ V}$, $G = +1$, 5 V step		16		μs
		To 0.01%, $V_S = 40 \text{ V}$, $G = +1$, 5 V step		22		
Overload recovery time	t_{OR}	$V_{IN} \times \text{Gain} > V_S$		10		μs

Electrical Characteristics (continued)

$V_S = 4.5 \text{ V to } 40 \text{ V}$, $T_A = +25 \text{ }^\circ\text{C}$, $V_{CM} = V_{OUT} = V_S/2$, and $R_L = 10 \text{ k}\Omega$ connected to $V_S/2$, unless otherwise noted. Boldface limits apply over the specified temperature range, $T_A = -40 \text{ }^\circ\text{C to } +125 \text{ }^\circ\text{C}$.

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
<i>OUTPUT</i>						
High output voltage swing	V_{OH}	$V_S = \pm 20 \text{ V}$, $R_L = 10 \text{ k}\Omega$	$+V_S - 1$			V
		$V_S = \pm 20 \text{ V}$, $R_L = 2 \text{ k}\Omega$	$+V_S - 1.2$			
Low output voltage swing	V_{OL}	$V_S = \pm 20 \text{ V}$, $R_L = 10 \text{ k}\Omega$	$-V_S + 60$			mV
		$V_S = \pm 20 \text{ V}$, $R_L = 2 \text{ k}\Omega$	$-V_S + 250$			
Short-circuit current	I_{SC}		± 45			mA
<i>POWER SUPPLY</i>						
Operating supply voltage	V_S	$T_A = -40 \text{ to } +125 \text{ }^\circ\text{C}$	4.5		40	V
Quiescent current (per amplifier)	I_Q	$V_S = 5 \text{ V}$	280			μA
		$V_S = 40 \text{ V}$	300			
<i>THERMAL CHARACTERISTICS</i>						
Operating temperature range	T_A		-40		+125	$^\circ\text{C}$
Package Thermal Resistance	θ_{JA}	SOIC-8L		125		$^\circ\text{C/W}$